TOSHIBA Photocoupler IRED & Photo-Triac

# TLP525G, TLP525G-2, TLP525G-4

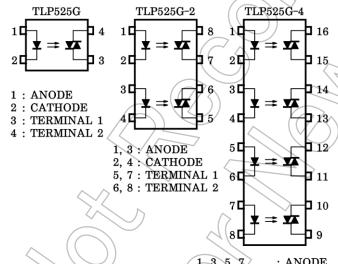
Triac Drive **Programmable Controllers** AC-Output Module Solid State Relay

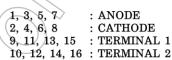
The TOSHIBA TLP525G, -2 and -4 consist of a photo-triac optically coupled to an infrared emitting diode.

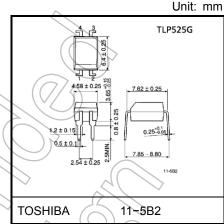
The TLP525G–2 offers two isolated channels in an eight lead plastic DIP package, while the TLP525G-4 provides four isolated channels in a sixteen lead plastic DIP package.

- Peak off-stage voltage: 400 V (min)
- Trigger LED current: 10 mA (max)
- Peak on-stage current: 2 Apk (max)
- Isolation voltage: 2500 V<sub>rms</sub> (min)
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A

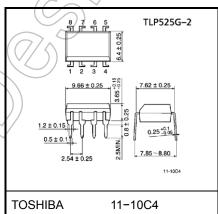
# File No.E67349 Pin Configurations (top view)



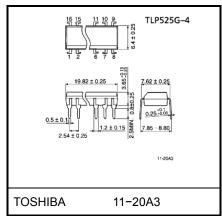




Weight: 0.26g (typ.)



Weight: 0.54g (typ.)



Weight: 1.1g (typ.)

Start of commercial production 1985-01

#### Absolute Maximum Ratings (Ta = 25°C)

| Characteristics             |   |                  |                              | Ra                                |                        |         |  |
|-----------------------------|---|------------------|------------------------------|-----------------------------------|------------------------|---------|--|
|                             |   |                  | Symbol                       | TLP525G                           | TLP525G-2<br>TLP525G-4 | Unit    |  |
|                             | Forward current   |                  | lF                           | 50                                | 50                     | mA      |  |
| TED                         | Forward current derating                                  |                  | I <sub>F</sub> / °C          | -0.7 (Ta ≥ 53°C) -0.5 (Ta ≥ 25°C) |                        | mA / °C |  |
|                             | Pulse forward current                                     |                  | IFP                          | 1 (100µs pu                       | А                      |         |  |
|                             | Reverse voltage   |                  | V <sub>R</sub>               | Į.                                | ) V                    |         |  |
|                             | Input power dissipation                                   |                  | PD                           | 50                                | 60                     | mW      |  |
|                             | Input power dissipation derating                          |                  | ΔP <sub>D</sub> /°C          | -0.69(Ta ≥ 53°C) -0.6(Ta ≥ 25°C)  |                        | mW/°C   |  |
|                             | Junction temperature                                      |                  | Tj                           | 12                                | °C                     |         |  |
|                             | Off-state output terminal voltage                         |                  | V <sub>DRM</sub>             | 40                                | V                      |         |  |
|                             | On atota DMS aurrent                                      | Ta = 25°C        | l=                           | 100                               | 80                     |         |  |
|                             | On-state RMS current                                      | Ta = 70°C        | TT (RMS)                     | 50                                | mA                     |         |  |
|                             | On–state current derating (Ta ≥ 25°C)                     |                  | I <sub>T</sub> / °C          | -1.1                              | -0.9                   | mA / °C |  |
| Detector                    | Peak on state current                                     |                  | ITP                          | 2 (100µs pu                       | A                      |         |  |
| Det                         | Peak non-repetitive surge current (P <sub>W</sub> = 10ms) |                  | ITSM                         | 1                                 | A                      |         |  |
|                             | Output power dissipation                                  |                  | Po                           | 300                               | 240                    | mW      |  |
|                             | Output power dissipation derating (Ta ≥ 25°C)             |                  | ΔP <sub>O</sub> /°C          | -3.0 -2.4                         |                        | mW / °C |  |
|                             | Junction temperature                                      |                  | 4                            | 1(15                              |                        | °C      |  |
| Stor                        | Storage temperature range                                 |                  | T <sub>stg</sub>             | -55 to 125                        |                        | °C      |  |
| Operating temperature range |   | Topr             | -40 to 100                   |                                   | °C                     |         |  |
| Lead soldering temperature  |   | T <sub>sol</sub> | 260 (10 s)                   |                                   | °C                     |         |  |
| Isolation voltage (Note)    |   | BVs              | 2500 (AC, 60 s, R.H. ≤ 60 %) |                                   | $V_{rms}$              |         |  |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note: Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

#### **Recommended Operating Conditions**

| Characteristic        | Symbol | Min | Тур. | Max | Unit |
|-----------------------|--------|-----|------|-----|------|
| Supply voltage        | VAC    | _   | _    | 120 | Vac  |
| Forward current       | lF     | 15  | 20   | 25  | mA   |
| Peak on-state current | ITP    | _   | _    | 1   | Α    |
| Operating temperature | Topr   | -25 | _    | 85  | °C   |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

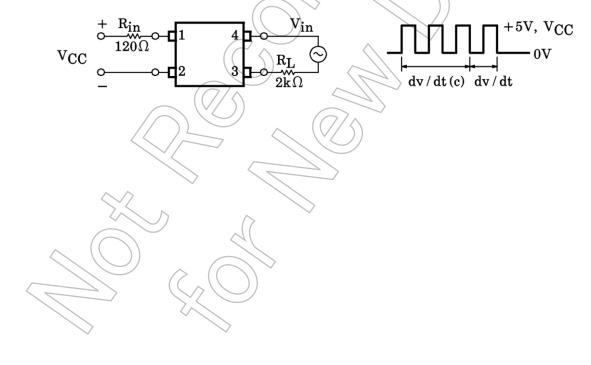
## **Individual Electrical Characteristics (Ta = 25°C)**

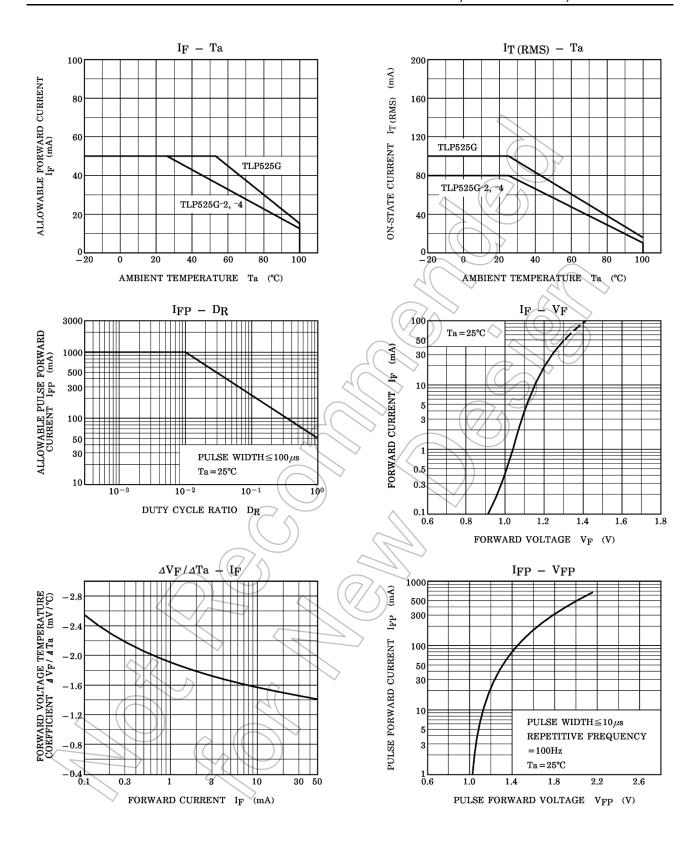
|          | Characteristic                               | Symbol           | Test Condition   | Min | Тур. | Max | Unit   |
|----------|--|------------------|--|-----|------|-----|--------|
| LED      | Forward voltage                              | VF               | I <sub>F</sub> = 10 mA   | 1.0 | 1.15 | 1.3 | V      |
|          | Reverse current                              | IR               | V <sub>R</sub> = 5 V   | _   | _    | 10  | μΑ     |
|          | Capacitance                                  | Ст               | VF = 0 V, f = 1 MHz  | _<  | 30   | _   | pF     |
|          | Peak off-state current                       | I <sub>DRM</sub> | V <sub>DRM</sub> = 400 V   | - ( | 10   | 100 | nA     |
| Detector | Peak on-state voltage                        | V <sub>TM</sub>  | I <sub>TM</sub> = 100 mA   | _   | 1.7  | 3.0 | V      |
|          | Holding current                              | ΙH               | _  |     | 0.6  | 1   | mA     |
|          | Critical rate of rise of off–state voltage   | dv / dt          | V <sub>in</sub> = 120 V <sub>rms</sub> , Ta = 85 °C<br>(Figure 1)            | 200 | 500  | 1   | V / μs |
|          | Critical rate of rise of commutating voltage | dv / dt (c)      | V <sub>in</sub> = 30 V <sub>rms</sub> , I <sub>T</sub> = 15 mA<br>(Figure 1) | J?  | 0.2  | _   | V / μs |

## **Coupled Electrical Characteristics (Ta = 25°C)**

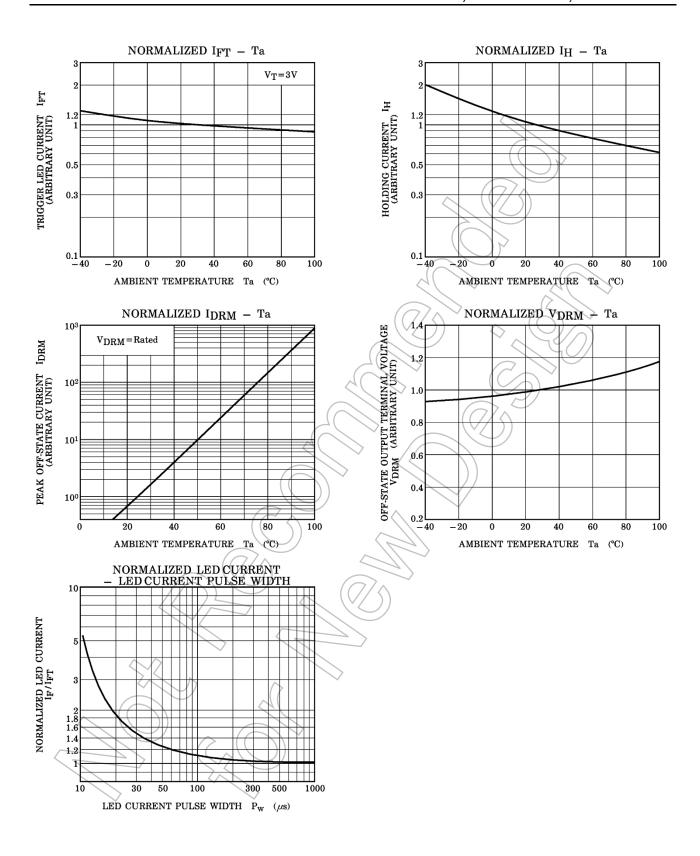
| Characteristic              | Symbol | Test Condition                      | Min. Typ.                           | Max. | Unit |
|-----------------------------|--------|-------------------------------------|-------------------------------------|------|------|
| Trigger LED current         | lfT    | VT = 3 V                            | - 5                                 | 10   | mA   |
| Capacitance input to output | Cs     | V <sub>S</sub> = 0 V, f = 1 MHz     | - 0.8                               | _    | pF   |
| Isolation resistance        | Rs     | V <sub>S</sub> = 500 V, R.H. ≤ 60 % | 5×10 <sup>10</sup> 10 <sup>14</sup> | _    | Ω    |
| Isolation voltage           | BVS    | AC, 60 s                            | 2500 —                              | _    | Vrms |

Fig.1 dv / dt Test Circuit





NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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